# **MPQ3413**



1.5A, 2.2MHz, 52μA I<sub>Q</sub>, 5V V<sub>OUT</sub>, Synchronous Step-Up Converter with Output Disconnect, AEC-Q100 Qualfied

#### DESCRIPTION

The MPQ3413 is a high-efficiency, synchronous, current mode, step-up converter with output disconnect.

The MPQ3413 can start up from an input voltage  $(V_{IN})$  as low as 2.8V, and provides inrush current limiting and output short-circuit protection (SCP). The integrated P-channel synchronous rectifier (SR) improves efficiency and eliminates the requirement of an external Schottky diode. The MPQ3413's P-channel MOSFET disconnects the output from the input when the MPQ3413 shuts down. The output disconnect feature allows the output to be discharged completely, allowing the MPQ3413 to draw a supply current below  $1\mu A$  in shutdown mode.

The 2.2MHz switching frequency (f<sub>SW</sub>) allows for smaller external components, while the internal compensation and soft start (SS) minimize the external component count. These features result in a compact solution across a wide current load range.

The MPQ3413 features an integrated power MOSFET that supports an 5V output voltage (V<sub>OUT</sub>) and a peak switching current above 1.5A.

The MPQ3413 is available in a small TSOT23-8 package.

#### **FEATURES**

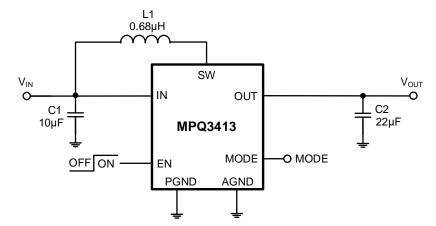
- Supports 5V/0.3A Average Output Current (I<sub>OUT</sub>)
- 2.8V to 4V Input Voltage (V<sub>IN</sub>) Range
- 5V Fixed Output Voltage (V<sub>OUT</sub>)
- Internal Synchronous Rectifier (SR)
- 2.2MHz Fixed Switching Frequency (f<sub>SW</sub>)
- 52µA Quiescent Current (I<sub>Q</sub>)
- <1µA Shutdown Current</li>
- True Output Disconnect from Input
- Up to 85% Efficiency
- Internal Compensation, Inrush Current Limiting, and Internal Soft Start (SS)
- Small External Components
- Over-Voltage Protection (OVP), Short-Circuit Protection (SCP), and Over-Temperature Protection (OTP)
- Available in a TSOT23-8 Package
- Available in AEC-Q100 Grade 1

#### APPLICATIONS

- Single-Cell, Li Battery Backup
- Automotive Secondary Regulation

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#### TYPICAL APPLICATION





## ORDERING INFORMATION

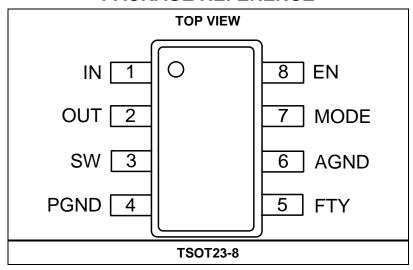
Part Number*	Package	Top Marking	MSL Rating
MPQ3413GJ-5-AEC1	TSOT23-8	See Below	1

<sup>\*</sup> For Tape & Reel, add suffix -Z (e.g. MPQ3413GJ-5-AEC1-Z).

# **TOP MARKING** BRFY

**BRF: Product code** Y: Year code

## PACKAGE REFERENCE





#### PIN FUNCTIONS

Pin #	Name	Description
1	IN	<b>Power supply input.</b> IN supplies the start-up bias and must be bypassed locally. When the output voltage (Vout) exceeds the input voltage (Vin), the OUT pin supplies the bias power to the MPQ3413.
2	OUT	<b>Output.</b> The OUT pin is the internal synchronous rectifier (SR) MOSFET's drain. OUT supplies the bias power when V <sub>OUT</sub> exceeds V <sub>IN</sub> . Keep the PCB trace from OUT to the output filter capacitor(s) as short and wide as possible. When EN is pulled low, the MPQ3413's output disconnect feature allows OUT to be completely disconnected from IN. OUT is also the sensing point for regulation.
3	SW	<b>Power MOSFET output.</b> SW is the connection node between the internal low-side MOSFET (LS-FET) and synchronous MOSFET. Connect the power inductor between SW and the input power. To reduce EMI and voltage spikes, keep the PCB trace as short and wide as possible.
4	PGND	Power ground.
5	FTY	Factory use only. Float FTY or connect it to ground in application.
6	AGND	Analog ground.
7	MODE	<b>Mode selection.</b> Pull MODE logic high to enable advanced asynchronous modulation (AAM) mode; pull this pin logic low to enter forced continuous conduction mode (FCCM). MODE should not be changed while the MPQ3413 is in operation.
8	EN	<b>Chip enable control input.</b> Pull EN above 1.2V to turn on the regulator; pull this pin below 0.4V to turn off the regulator.

# ABSOLUTE MAXIMUM RATINGS (1)

SW, OUT	0.3V to +6.5V
SW (<5ns)	0.3V to +9V
All other pins	0.3V to +6.5V
Continuous power dissipation (	$T_A = 25^{\circ}C)^{(2)}$
	1.25W
Junction temperature	
Lead temperature	260°C
Storage temperature	65°C to +150°C

#### ESD Ratings

Human	body model	(HBM)	±2kV
Charge	d device mod	lel (CDM)	)±750V

#### Recommended Operating Conditions (3)

Supply voltage (V <sub>IN</sub> )	2.8V to 4V (4)
Enable voltage (V <sub>EN</sub> )	0V to 4V
Operating junction temp (	T <sub>J</sub> )40°C to +125°C

# **Thermal Resistance** <sup>(5)</sup> **θ**<sub>JA</sub> **θ**<sub>JC</sub> TSOT23-8 ......100 .... 55 ... °C/W

#### Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature,  $T_J$  (MAX), the junction-to-ambient thermal resistance,  $\theta_{JA}$ , and the ambient temperature,  $T_A$ . The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_D$  (MAX) =  $(T_J$  (MAX)  $T_A$ ) /  $\theta_{JA}$ . Exceeding the maximum allowable power dissipation can generate an excessive die temperature, which may cause the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 4) If V<sub>IN</sub> is close to V<sub>OUT</sub>, the boost converter may trigger minimum on time. When V<sub>IN</sub> exceeds V<sub>OUT</sub>, the boost converter switches between boost mode and linear charge mode. Both conditions result in a V<sub>OUT-RIPPLE</sub> that is too high. Therefore, this is not recommended.
- 5) Measured on JESD51-7, 4-layer PCB.



## **ELECTRICAL CHARACTERISTICS**

 $V_{IN} = V_{EN} = 3.3V$ ,  $V_{OUT} = 5V$ ,  $T_J = -40^{\circ}C$  to +125°C, typical values are tested at  $T_J = 25^{\circ}C$ , unless otherwise noted.

Parameters	Symbol	Condition	Min	Тур	Max	Units
Voltage Range		•	•			
Quiescent current	lα	$\begin{aligned} &V_{\text{MODE}} = V_{\text{EN}} = V_{\text{IN}} = 3.3V, \\ &V_{\text{OUT}} = 6V, \text{ no load,} \\ &\text{measured on OUT, T}_{\text{J}} = 25^{\circ}\text{C} \end{aligned}$		52	80	μΑ
Quiescent current	IQ	$\begin{split} &V_{\text{MODE}} = V_{\text{EN}} = V_{\text{IN}} = 3.3V, \\ &V_{\text{OUT}} = 6V, \text{ no load,} \\ &\text{measured on IN, } T_{\text{J}} = 25^{\circ}\text{C} \end{split}$		8	14	μΑ
Shutdown current	I <sub>SD</sub>	$V_{EN} = V_{OUT} = 0V$ , measured on IN, $T_J = 25$ °C		0.1	1	μΑ
IN under-voltage lockout (UVLO) threshold	$V_{\text{IN\_UVLO}}$	$V_{IN}$ rising, $T_J = 25^{\circ}C$		1.65	1.7	V
IN UVLO hysteresis				100		mV
Step-Up Converter						
Operation frequency	f <sub>SW</sub>		1.9	2.2	2.5	MHz
V voltage reference	V <sub>REG</sub>	T <sub>J</sub> = 25°C	4.9	5	5.1	V
Vou⊤ voltage reference		T <sub>J</sub> = -40°C to +125°C	4.875	5	5.125	V
N-channel MOSFET on resistance	R <sub>DS(ON)_N</sub>			70		mΩ
N-channel MOSFET leakage current	I <sub>N_LK</sub>	V <sub>SW</sub> = 6.5V, T <sub>J</sub> = 25°C		0.1	1	μA
P-channel MOSFET on resistance	R <sub>DS(ON)_P</sub>			80		mΩ
P-channel MOSFET leakage current	I <sub>P_LK</sub>	V <sub>SW</sub> = 6.5V, V <sub>OUT</sub> = 0V, T <sub>J</sub> = 25°C		0.1	1	μΑ
Maximum duty cycle	D <sub>MAX</sub>	V <sub>IN</sub> = 3.3V		85		%
		V <sub>IN</sub> = 4V, V <sub>OUT</sub> = 0V	0.1	0.3	0.4	Α
Start-up current limit	Ist_LIMIT	V <sub>IN</sub> = 4V, V <sub>OUT</sub> setting = 3.6V, pull V <sub>OUT</sub> to 3.3V	0.4	0.8	1	Α
N-channel MOSFET current limit	Isw_LIMIT	Duty = 40%	2.5	3.6	4.5	Α
Logic Interface		1				
EN input high voltage	V <sub>EN_H</sub>		1.2			V
EN input low voltage	V <sub>EN_L</sub>				0.4	V
EN input current	I <sub>EN</sub>	Connect to V <sub>IN</sub>		10		nA
Protections		•	•			
Thermal shutdown (6)			150	160	175	°C
Over-temperature hysteresis (6)				25		°C

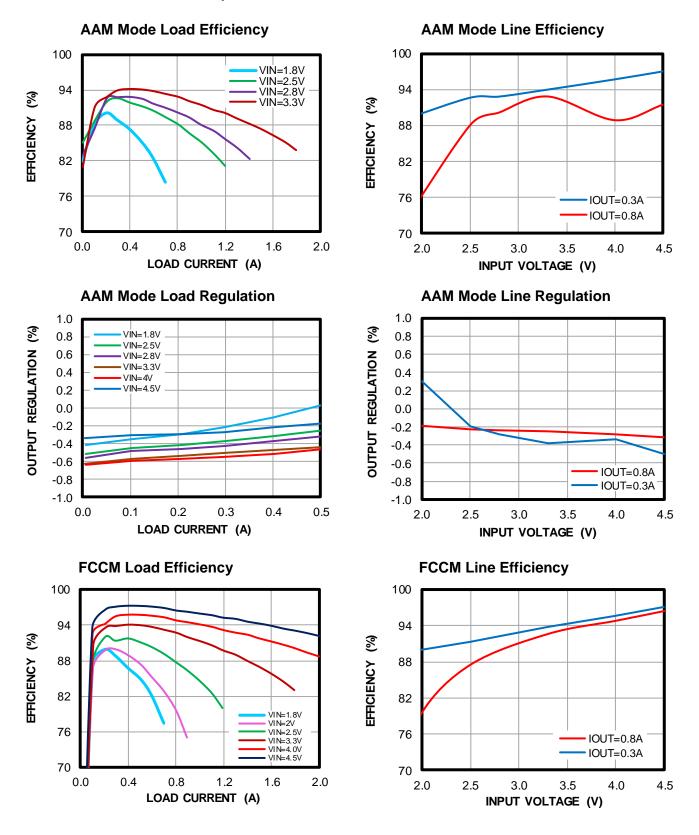
#### Note:

6) Guaranteed by characterization. Not tested in production.



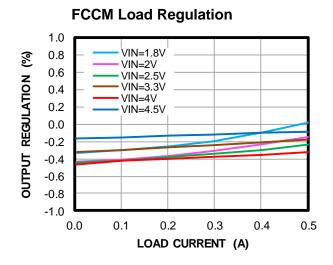
## TYPICAL PERFORMANCE CHARACTERISTICS

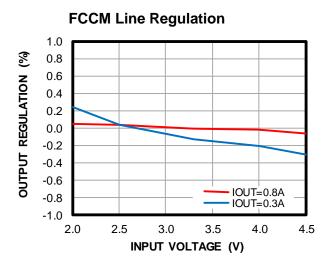
 $V_{IN}$  = 3.3V,  $V_{OUT}$  = 5V, L = 0.68 $\mu$ H,  $T_A$  = 25°C, unless otherwise noted.

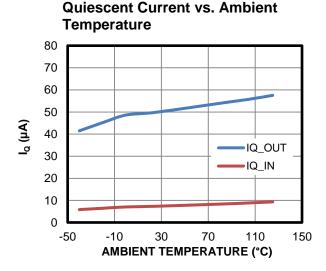


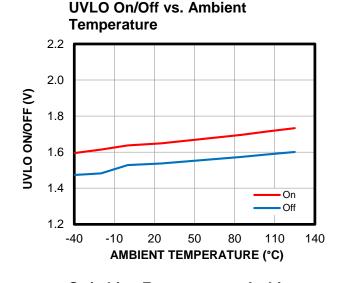


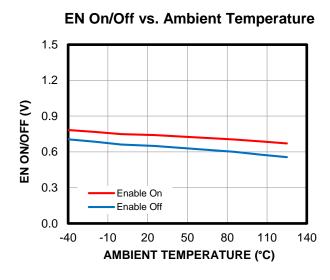
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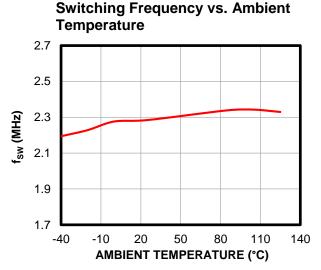






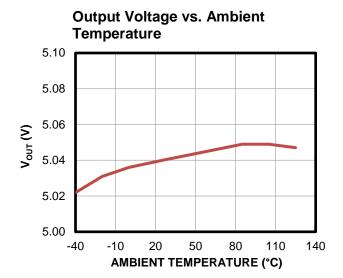


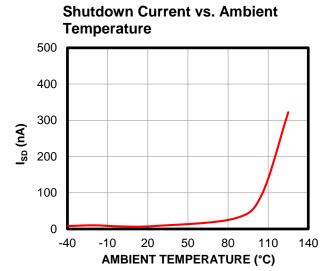






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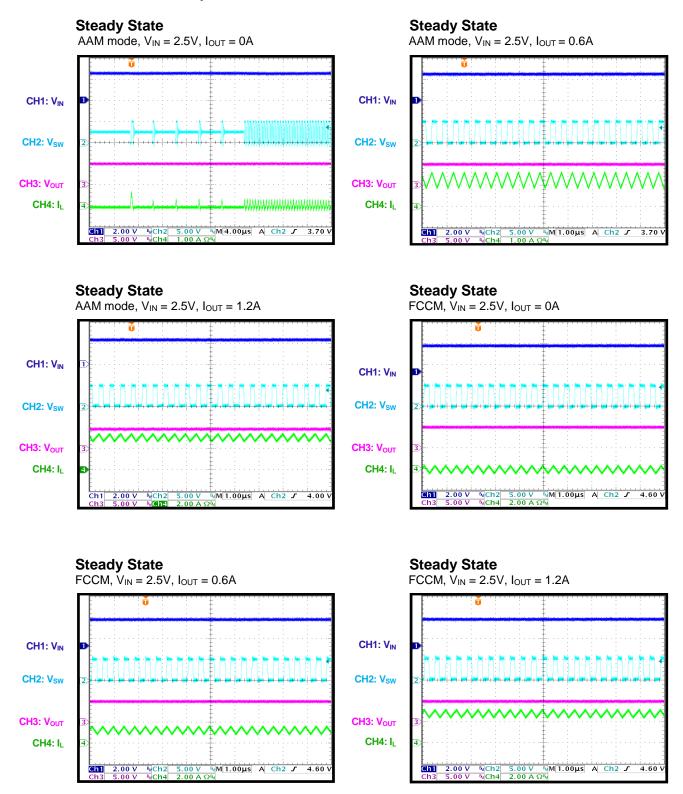




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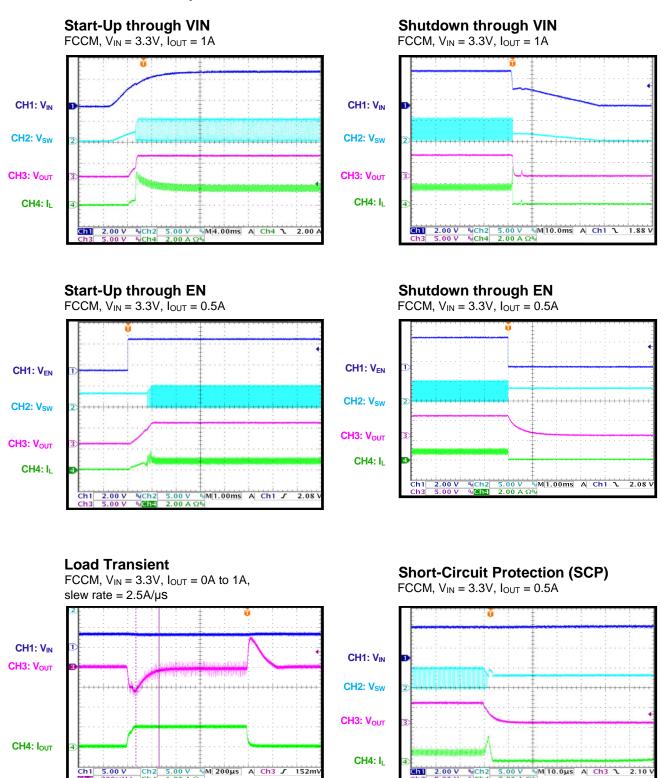
 $V_{IN} = 3.3V$ ,  $V_{OUT} = 5V$ ,  $L = 0.68\mu H$ ,  $T_A = 25^{\circ}C$ , unless otherwise noted.



8



 $V_{\text{IN}}$  = 3.3V,  $V_{\text{OUT}}$  = 5V, L = 0.68 $\mu$ H,  $T_{\text{A}}$  = 25°C, unless otherwise noted.



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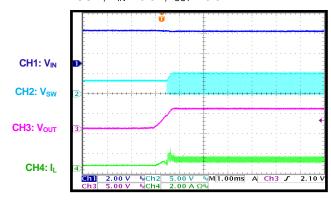
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 $V_{IN} = 3.3V$ ,  $V_{OUT} = 5V$ ,  $L = 0.68\mu H$ ,  $T_A = 25^{\circ}C$ , unless otherwise noted.

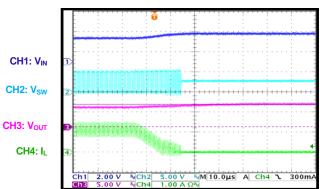
#### **SCP Recovery**

FCCM,  $V_{IN} = 3.3V$ ,  $I_{OUT} = 0.5A$ 



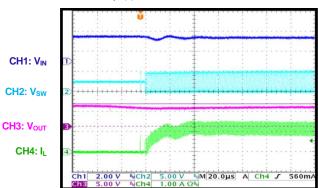
#### **Over-Voltage Protection (OVP)**

 $V_{IN} = 2.5V$ ,  $I_{OUT} = 0.5A$ 



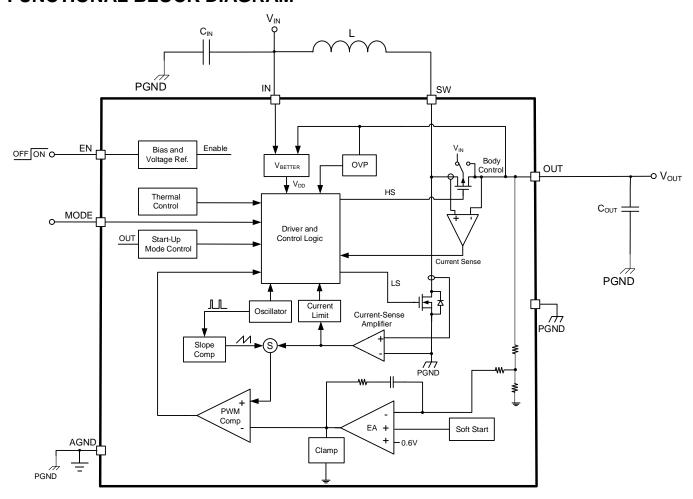
## **OVP Recovery**

 $V_{IN} = 2.5V$ ,  $I_{OUT} = 0.5A$ 





# **FUNCTIONAL BLOCK DIAGRAM**



**Figure 1: Functional Block Diagram** 



#### **OPERATION**

The MPQ3413 is a 2.2MHz, synchronous stepup converter in a compact TSOT23 package with true output disconnect. The MPQ3413 features fixed-frequency, current-mode, pulse-width modulation (PWM) control to achieve good line and load regulation.

Internal soft start (SS) and loop compensation simplify the design process and minimize the number of required external components. The internal low on resistance ( $R_{DS(ON)}$ ) MOSFETs, combined with frequency stretching, allow the MPQ3413 to maintain high efficiency across a wide current load range.

#### Start-Up

When enabled, the MPQ3413 starts up in linear-charge mode. During linear charge, the rectified P-channel MOSFET turns on until the output voltage ( $V_{\text{OUT}}$ ) is charged close to the input volage ( $V_{\text{IN}}$ ).

To avoid inrush current, the P-channel MOSFET current is limited to about 0.3A (when  $V_{\text{OUT}}$  is 0V). The P-channel MOSFET linear charge current limit increases to about 0.8A while  $V_{\text{OUT}}$  rises to 3.3V (if  $V_{\text{IN}}$  exceeds 3.3V). This circuit helps limit the output current ( $I_{\text{OUT}}$ ) under short-circuit conditions.

When  $V_{\text{OUT}}$  reaches  $V_{\text{IN}}$ , the linear charging period completes and the device starts switching.  $V_{\text{OUT}}$  starts to rise under internal SS control. Under boost switching conditions, the current limit is typically 3.6A.

When  $V_{OUT}$  exceeds  $V_{IN}$ , the MPQ3413 powers its internal circuits from  $V_{OUT}$  instead of  $V_{IN}$ . This allows for strong driving capabilities and high efficiency, even if  $V_{IN}$  drops as low as 1.8V.

#### Soft Start (SS)

The MPQ3413 provides SS by charging an internal capacitor using a current source. During the linear charging period, the SS signal continues rising, following the feedback (FB) signal. When the linear charge completes, the voltage on the SS capacitor ( $C_{SS}$ ) is charged and ramps up the reference voltage ( $V_{REF}$ ) based on the internal fixed slew rate.  $C_{SS}$  is discharged completely during shutdown, thermal shutdown, and output short circuit.

#### Enable (EN)

The MPQ3413 begins operating if EN is pulled above 1.2V. If EN is pulled below 0.4V, then the device enters shutdown mode. In shutdown mode, the regulator stops switching, all internal control circuits switch off, and the output disconnects from the input completely.

#### Power-Save Mode (PSM)

The MPQ3413 enters power-save mode (PSM) automatically if the MODE pin is pulled logic high when the load decreases. The device switches back to pulse-width modulation (PWM) mode when the load increases.

In PSM, the converter stretches the frequency down to save switching and driver losses. Additionally, the switching frequency ( $f_{SW}$ ) is stretched down when  $V_{IN}$  is close to  $V_{OUT}$ , which then triggers the minimum on time if maintained at a 2.2MHz frequency. This helps decrease the output ripple by avoiding group-pulse mode. Under very light-load conditions, the MPQ3413 continues to operate in group-pulse mode to regulate  $V_{OUT}$  and save more power.

If MODE is pulled logic low, the MPQ3413 operates in forced continuous conduction mode (FCCM), resulting in a consistent frequency across the entire load range.

Changing the mode setting from PSM to FCCM during operation may cause a disturbance in  $V_{\text{OUT}}$ . Therefore, it is recommended to not change MODE during operation.

#### **Error Amplifier (EA)**

The error amplifier (EA) is an internally compensated amplifier. The EA compares the internal 0.6V  $V_{REF}$  against the FB voltage ( $V_{FB}$ ) to generate an EA signal, which in turn controls the MPQ3413's  $V_{OUT}$ , fixed at 5V.

#### **Current Sensing**

Under linear charging conditions, the high-side P-channel MOSFET current is sensed and compared with the current limit threshold. The compared output regulates the linear charge current.

Under boost switching conditions, lossless current sensing converts the N-channel MOSFET current signal into a voltage that is



combined with the internal slope compensation. The total signal is compared with the EA output to provide peak current control for PWM. The peak MOSFET current is limited to approximately 3.6A. The MOSFET current signal is blanked internally for 60ns to enhance noise immunity.

#### **Output Disconnect**

The MPQ3413 is designed to allow a true output disconnect by eliminating the internal P-channel MOSFET rectifier's body diode conduction. This allows  $V_{\text{OUT}}$  to reach 0V during shutdown, drawing zero current from the input source.

This also allows for inrush current limiting at start-up, which minimizes the input supply's surge current. To achieve the advantages of output disconnect, do not connect an external Schottky diode between SW and  $V_{\text{OUT}}$ .

#### **Overload and Short-Circuit Protection (SCP)**

 $V_{\text{OUT}}$  drops when an overload or a short circuit occurs. If  $V_{\text{OUT}}$  drops below  $V_{\text{IN}}$  (0.3V), the MPQ3413 stops for about 50µs and then operates in linear-charge mode at start-up. If the overload or short circuit is removed, the MPQ3413 restarts automatically with a SS.

#### **Over-Voltage Protection (OVP)**

If  $V_{\text{OUT}}$  exceeds the typical 6V threshold, boost switching stops. After  $V_{\text{OUT}}$  drops to about 5.7V, switching recovers automatically. This protects the internal power MOSFET from over-voltage stress.

#### Thermal Shutdown

The MPQ3413 supports internal temperature monitoring. If the die temperature exceeds 155°C, the converter turns off. Once the temperature drops below 130°C, the converter restarts and resumes normal operation.



#### APPLICATION INFORMATION

#### **Selecting the Input Capacitor**

A low-ESR input capacitor ( $C_{IN}$ ) reduces input switching noise and the peak current drawn from the battery. Ceramic capacitors are recommended for input decoupling, and should be placed as close to the device as possible. A ceramic capacitor above  $10\mu F$  is recommended to limit the  $V_{IN}$  ripple.

#### **Selecting the Output Capacitor**

To ensure stability across the full operating range, the output capacitor ( $C_{\text{OUT}}$ ) requires a minimum 22µF capacitance at the configured  $V_{\text{OUT}}$ . A higher capacitance may be required to reduce the output and transient ripple. Low-ESR capacitors, such as X5R or X7R capacitors, are recommended. To support the ripple in PWM when the ESR is zero, the minimum  $C_{\text{OUT}}$  can be calculated using Equation (1):

$$C_{\text{OUT}} \ge \frac{I_{\text{OUT}} \times (V_{\text{OUT}(\text{MAX})} - V_{\text{IN}(\text{MIN})})}{f_{\text{SW}} \times V_{\text{OUT}(\text{MAX})} \times \Delta V_{\text{OUT}}}$$
(1)

Where  $V_{\text{OUT}(\text{MAX})}$  is the maximum output voltage,  $V_{\text{IN}(\text{MIN})}$  is the minimum input voltage,  $I_{\text{OUT}}$  is the output current,  $f_{\text{SW}}$  is the switching frequency, and  $\Delta V_{\text{OUT}}$  is the acceptable output voltage ripple.

A 1 $\mu$ F ceramic capacitor is recommended between  $V_{\text{OUT}}$  and PGND with a short loop. This reduces spikes on SW and improves EMI performance.

#### Selecting the Inductor

The MPQ3413 utilizes small surface-mount chip inductors due to the 2.2MHz  $f_{SW}$ . Inductances between 0.47 $\mu$ H and 1.2 $\mu$ H are suitable for most applications. Larger inductances allow for improved  $I_{OUT}$  capabilities by reducing the inductor ripple current. However, larger inductances increase the component size. The minimum inductance (L) can be calculated using Equation (2):

$$L \ge \frac{V_{\text{IN(MIN)}} \times (V_{\text{OUT(MAX)}} - V_{\text{IN(MIN)}})}{V_{\text{OUT(MAX)}} \times \Delta I_{L} \times f_{\text{SW}}}$$
(2)

Where  $\Delta I_{\perp}$  is the acceptable inductor current ripple.

Typically,  $\Delta I_L$  is set to be 30% to 50% of the maximum inductor current. A low DCR must be maintained to reduce resistive power loss. The saturated current ( $I_{SAT}$ ) should be large enough to support the peak current.

## **Design Example**

Table 1 shows a design example following the application guidelines for the recommended specifications.

**Table 1: Design Example** 

V <sub>IN</sub>	V <sub>OUT</sub>	l <sub>оит</sub>		
2.8V to 4V	5V	0A to 0.3A		

Figure 3 on page 16 shows the detailed application schematic and basis for the typical performance waveforms at  $V_{\text{OUT}} = 5V$ . For additional device applications, refer to the related evaluation board datasheet.



#### **PCB Layout Guidelines**

Efficient PCB layout is critical for high-frequency switching power supplies. Poor layout can result in reduced performance, excessive EMI, resistive loss, system instability, and even overvoltage stress. For the best results, refer to Figure 2 and follow the guidelines below:

- Place C<sub>OUT</sub> as close as possible to OUT and PGND.
- Place a small decoupling capacitor in parallel with the bulk C<sub>OUT</sub>. Place the small decoupling capacitor as close as possible to OUT and PGND. This is very important to reduce the spikes on SW and improve EMI performance.
- Place C<sub>IN</sub> and the inductor as close as possible to IN and SW. The trace between the inductor and SW should be as wide and short as possible.

- 4. Place the feedback (FB) loop far away from all noise sources such as SW. The FB divider resistors should be as close as possible to FB and AGND.
- 5. Tie the ground returns for  $C_{\text{IN}}$  and  $C_{\text{OUT}}$  as close as possible to PGND using a large copper GND area. Vias around GND are recommended to lower the die temperature.

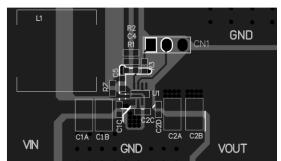


Figure 2: Recommended PCB Layout



# TYPICAL APPLICATION CIRCUIT

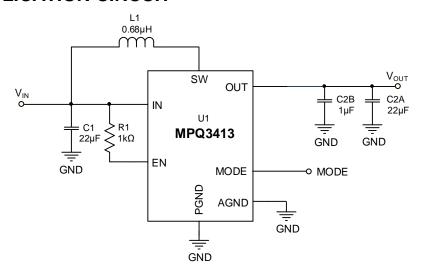
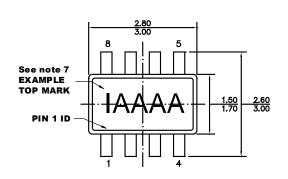


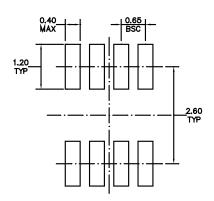
Figure 3: Typical Boost Application Circuit (V<sub>IN</sub> = 2.8V to 4V, V<sub>OUT</sub> = 5V, I<sub>OUT</sub> = 0A to 0.3A)



## **PACKAGE INFORMATION**

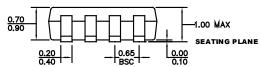
#### **TSOT23-8**



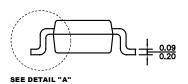


#### **TOP VIEW**

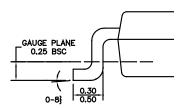
**RECOMMENDED LAND PATTERN** 







#### **SIDE VIEW**



**FRONT VIEW** 

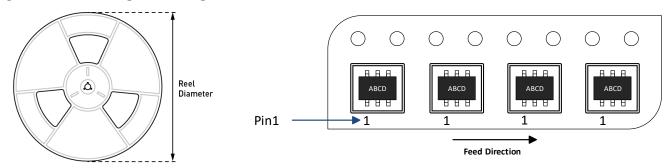
**DETAIL "A"** 

#### **NOTES:**

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSION, OR GATE BURR.
- 3) PACKAGE WIDTH DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.10 MILLIMETERS MAX.
- 5) JEDEC REFERENCE IS MO-193, VARIATION BA.
- 6) DRAWING IS NOT TO SCALE.
- 7) PIN 1 IS LOWER LEFT PIN WHEN READING TOP MARK FROM LEFT TO RIGHT (SEE EXAMPLE TOP MARK).



# **CARRIER INFORMATION**



Part Number	Package	Quantity/	Quantity/	Quantity/	Reel	Carrier	Carrier
	Description	Reel	Tube	Tray	Diameter	Tape Width	Tape Pitch
MPQ3413GJ-5- AEC1-Z	TSOT23-8	3000	N/A	N/A	7in	8mm	4mm



# **REVISION HISTORY**

Revision #	Revision Date	Description	Pages Updated
1.0	2/10/2022	Initial Release	-

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